



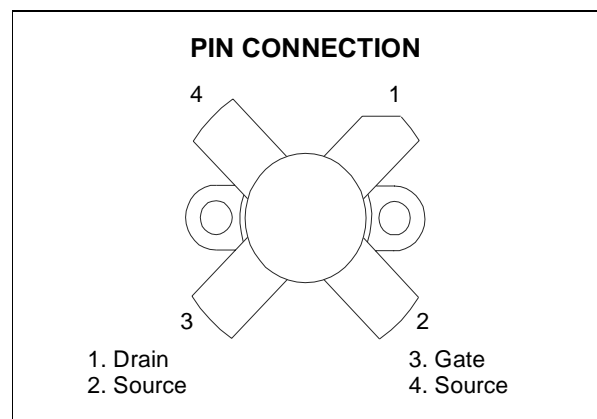
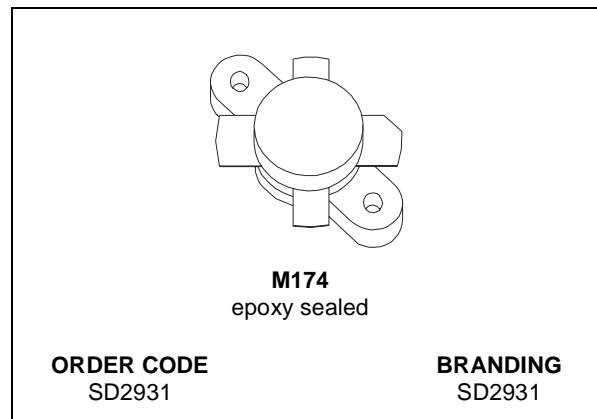
SD2931

RF POWER TRANSISTORS HF/VHF/UHF N-CHANNEL MOSFETs

- GOLD METALLIZATION
- EXCELLENT THERMAL STABILITY
- COMMON SOURCE CONFIGURATION
- $P_{OUT} = 150\text{ W MIN. WITH } 14\text{ dB GAIN @ } 175\text{ MHz}$

DESCRIPTION

The SD2931 is a gold metallized N-Channel MOS field-effect RF power transistor. It is intended for use in 50 V dc large signal applications up to 230 MHz.



ABSOLUTE MAXIMUM RATINGS ($T_{CASE} = 25\text{ }^{\circ}\text{C}$)

Symbol	Parameter	Value	Unit
$V_{(BR)DSS}$	Drain Source Voltage	125	V
V_{DGR}	Drain-Gate Voltage ($R_{GS} = 1M\Omega$)	125	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current	20	A
P_{DISS}	Power Dissipation	292	W
T_j	Max. Operating Junction Temperature	200	$^{\circ}\text{C}$
T_{STG}	Storage Temperature	-65 to +150	$^{\circ}\text{C}$

THERMAL DATA

$R_{th(j-c)}$	Junction -Case Thermal Resistance	0.6	$^{\circ}\text{C/W}$
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ELECTRICAL SPECIFICATION ($T_{CASE} = 25^{\circ}C$)

STATIC

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
$V_{(BR)DSS}$	$V_{GS} = 0\text{ V}$	$I_{DS} = 100\text{ mA}$	125			V
I_{DSS}	$V_{GS} = 0\text{ V}$	$V_{DS} = 50\text{ V}$			5	mA
I_{GSS}	$V_{GS} = 20\text{ V}$	$V_{DS} = 0\text{ V}$			5	μA
$V_{GS(Q)*}$	$V_{DS} = 10\text{ V}$	$I_D = 250\text{ mA}$	1.5		4.0	V
$V_{DS(ON)}$	$V_{GS} = 10\text{ V}$	$I_D = 10\text{ A}$			3.0	V
G_{FS}	$V_{DS} = 10\text{ V}$	$I_D = 5\text{ A}$	5			mho
C_{ISS}	$V_{GS} = 0\text{ V}$	$V_{DS} = 50\text{ V}$		480		pF
C_{OSS}	$V_{GS} = 0\text{ V}$	$V_{DS} = 50\text{ V}$		190		pF
C_{RSS}	$V_{GS} = 0\text{ V}$	$V_{DS} = 50\text{ V}$		18		pF

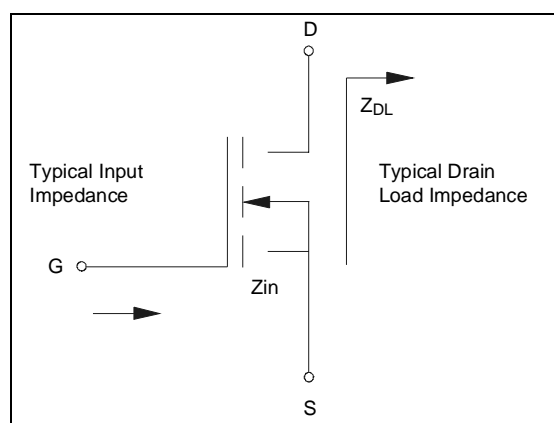
* $V_{GS(Q)}$ sorted with alpha/numeric code marked on unit.

REF. 7163910B

DYNAMIC

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
P_{OUT}	$V_{DD} = 50\text{ V}$	$I_{DQ} = 250\text{ mA}$ $f = 175\text{ MHz}$	150			W
G_{PS}	$V_{DD} = 50\text{ V}$	$I_{DQ} = 250\text{ mA}$ $P_{OUT} = 150\text{ W}$ $f = 175\text{ MHz}$	14	15		dB
η_D	$V_{DD} = 50\text{ V}$	$I_{DQ} = 250\text{ mA}$ $P_{OUT} = 150\text{ W}$ $f = 175\text{ MHz}$	55	65		%
Load Mismatch	$V_{DD} = 50\text{ V}$	$I_{DQ} = 250\text{ mA}$ $P_{OUT} = 150\text{ W}$ $f = 175\text{ MHz}$ All Phase Angles	10:1			VSWR

IMPEDANCE DATA



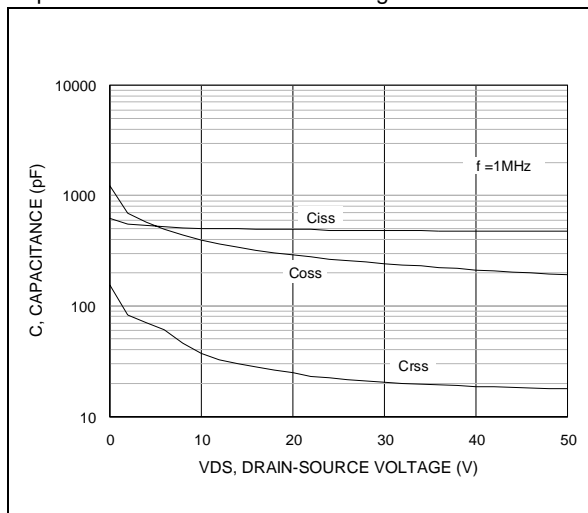
FREQ	$Z_{IN} (\Omega)$	$Z_{DL} (\Omega)$
30 MHz	$1.7 - j 5.7$	$6.8 + j 0.9$
175 MHz	$1.2 - j 2.0$	$2.0 + j 2.4$

 V_{GS} SORTS

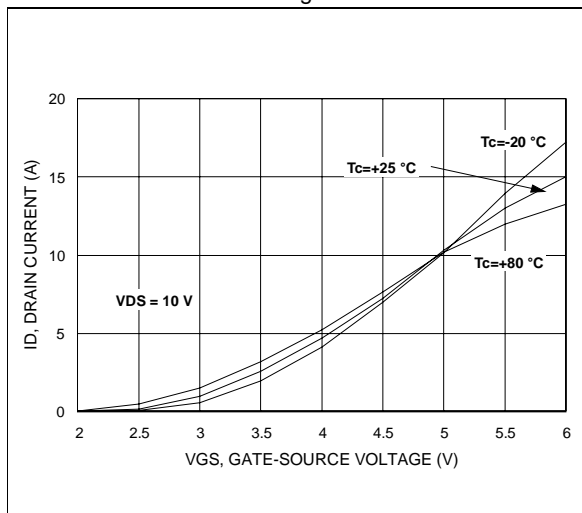
AA	1.5 - 1.6	J	2.8 - 2.9
BB	1.6 - 1.7	K	2.9 - 3.0
CC	1.7 - 1.8	L	3.0 - 3.1
DD	1.8 - 1.9	M	3.1 - 3.2
EE	1.9 - 2.0	N	3.2 - 3.3
A	2.0 - 2.1	P	3.3 - 3.4
B	2.1 - 2.2	Q	3.4 - 3.5
C	2.2 - 2.3	R	3.5 - 3.6
D	2.3 - 2.4	S	3.6 - 3.7
E	2.4 - 2.5	T	3.7 - 3.8
F	2.5 - 2.6	U	3.8 - 3.9
G	2.6 - 2.7	V	3.9 - 4.0
H	2.7 - 2.8		

TYPICAL PERFORMANCE

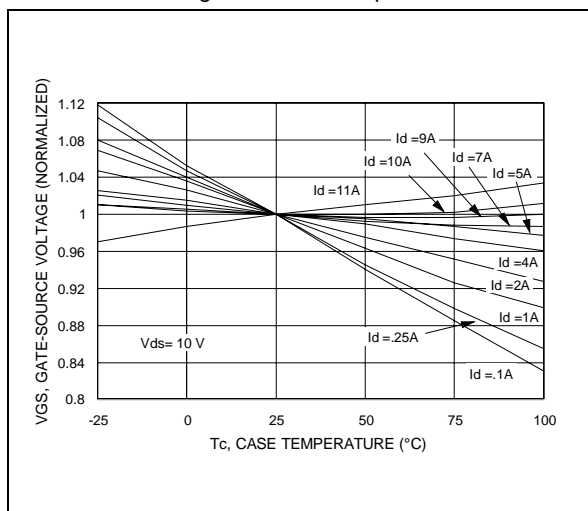
Capacitance vs. Drain-Source Voltage



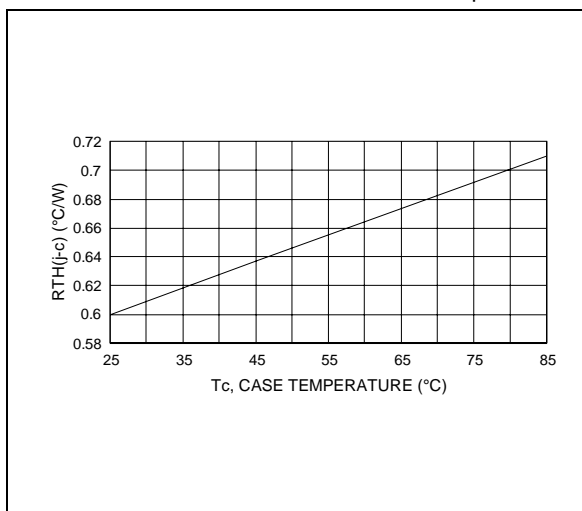
Drain Current vs. Gate Voltage



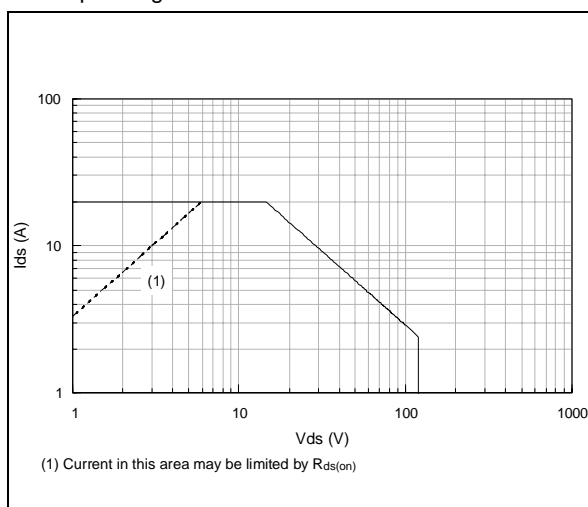
Gate-Source Voltage vs. Case Temperature



Maximum Thermal Resistance vs. Case Temperature

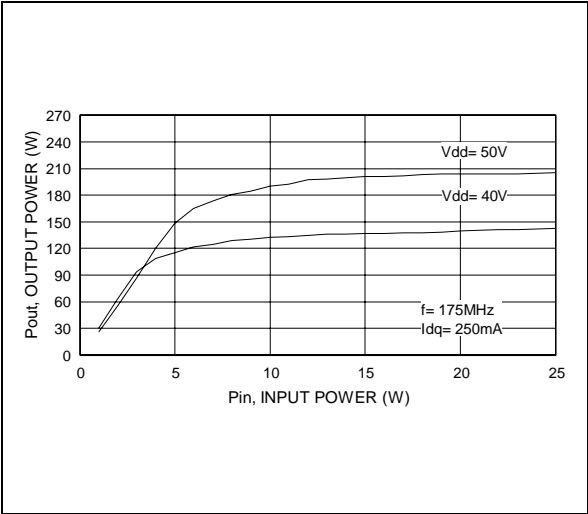


Safe Operating Area

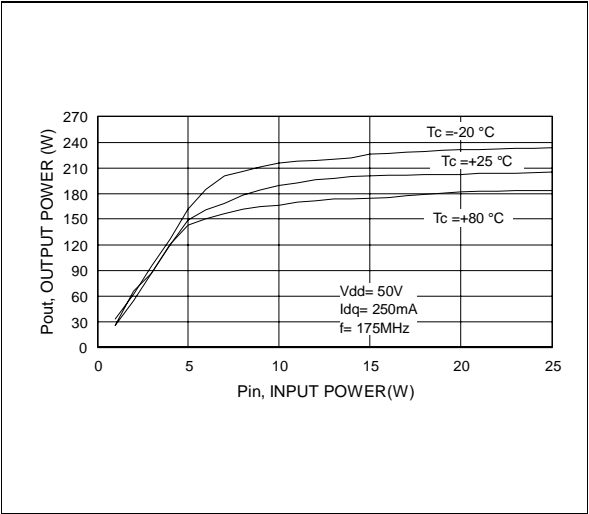


TYPICAL PERFORMANCE (175 MHz)

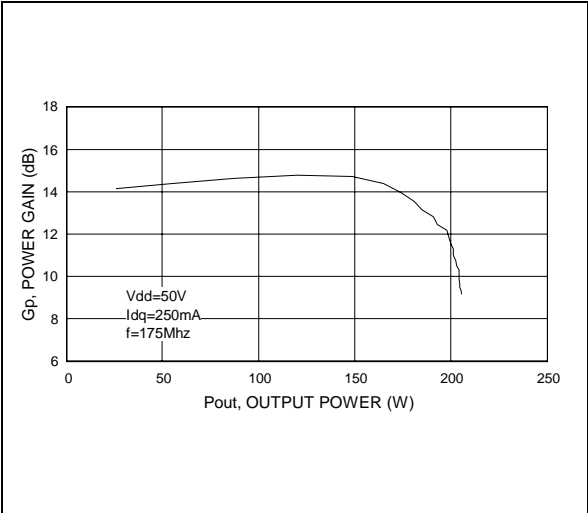
Output Power vs. Input Power



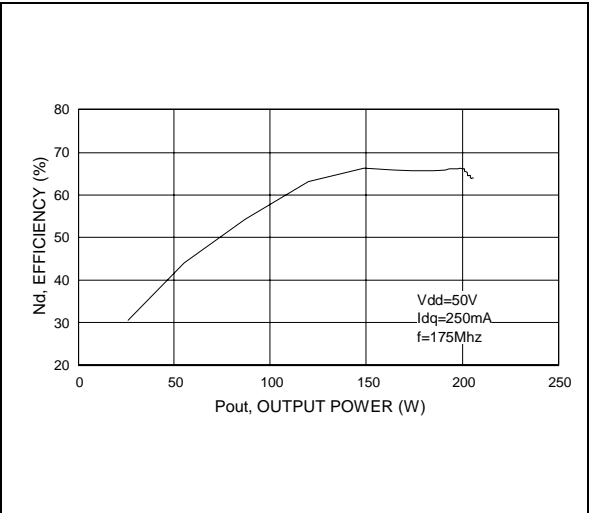
Output Power vs. Input Power



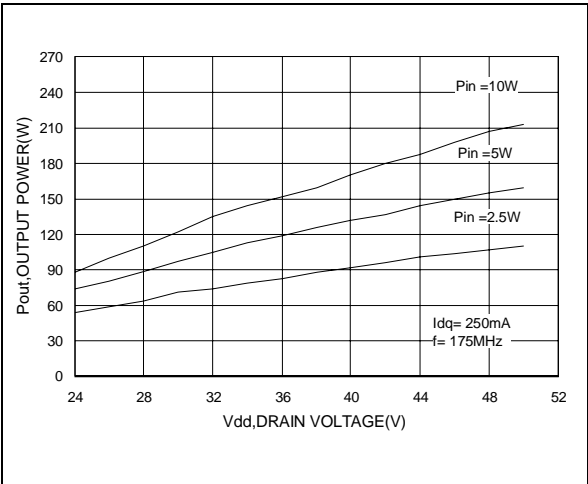
Power Gain vs. Output Power



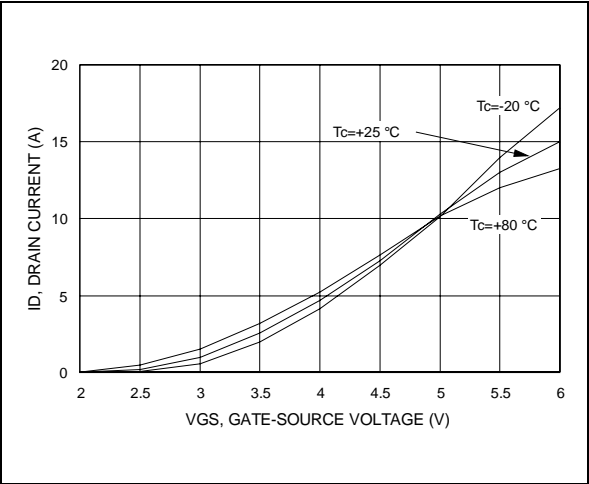
Efficiency vs. Output Power



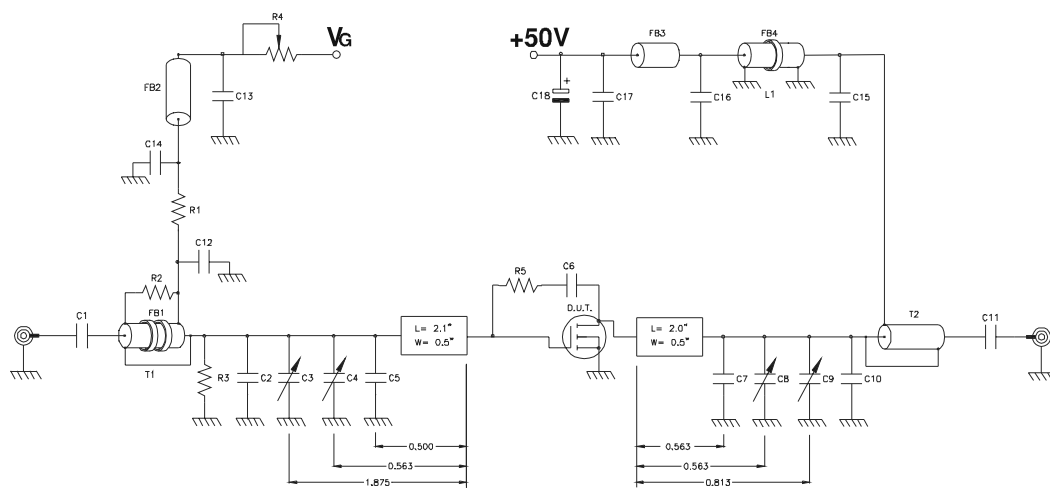
Output Power vs. Supply Voltage



Drain Current vs. Gate-Source Voltage



175 MHz Test Circuit Schematic (Production Test Circuit)



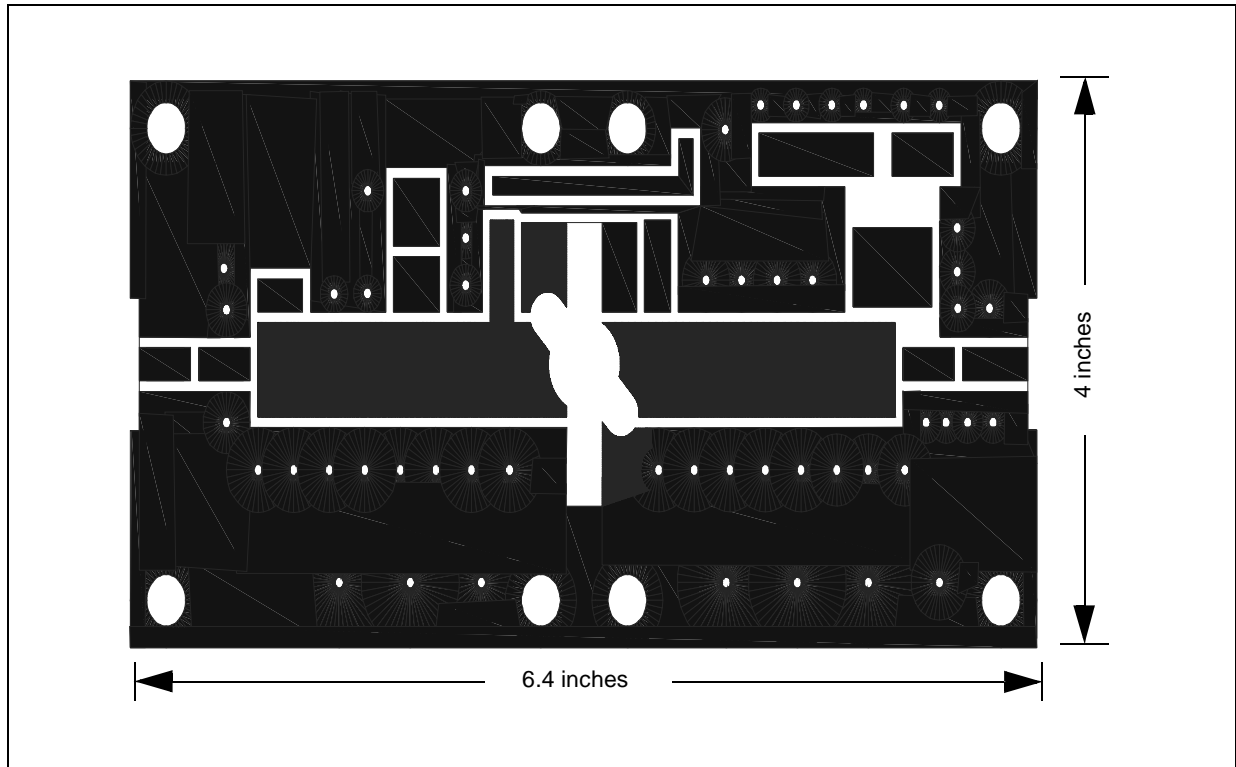
Note: All dimensions in inches

REF. 1021579C

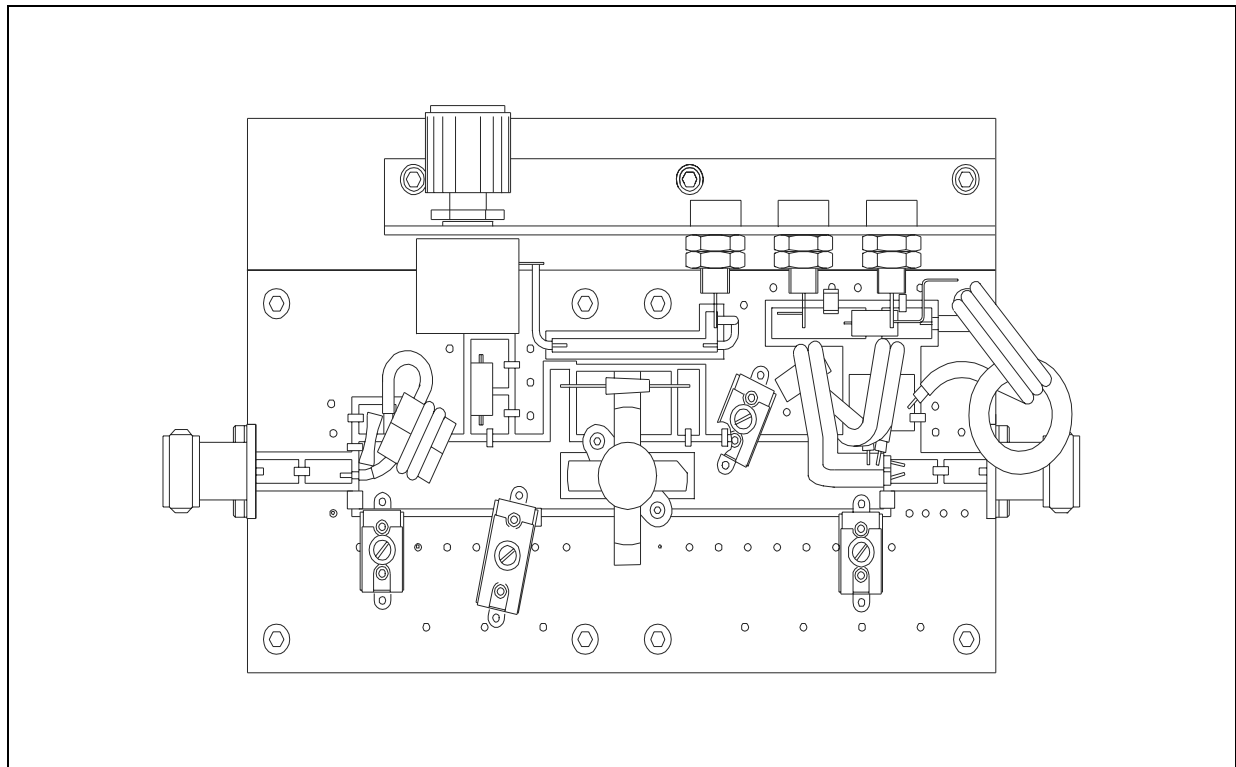
175 MHz Test Circuit Component Part List

T1	4:1 Transformer, 25 ohm Flexible Coax .090 OD 6" Long
T2	1:4 Transformer, 25 ohm Semi-Rigid Coax .141 OD 6" Long
FB1	Toroid X 2, 0.5" OD .312" ID 850μ 2 Turns
FB2, FB3	VK200
FB4	Shield Bead, 1" OD 0.5" ID 850μ 3 Turns
L1	1/4 Wave Choke, 50 ohm Semi-Rigid Coax .141 OD 12" Long
PCB	0.62" Woven Fiberglass, 1 oz. Copper, 2 Sides, $\epsilon_r = 2.55$
R1, R3	470 ohm 1 W Chip Resistor
R2	360 ohm 1/2 W Resistor
R4	20 Kohm 10 Turn Potentiometer
R5	560 ohm 1 W Resistor
C1, C11	470 pF ATC Chip Cap
C2	43 pF ATC Chip Cap
C3, C8, C9	Arco 404, 12-65 pF
C4	Arco 423, 16-100 pF
C5	120 pF ATC Chip Cap
C6	0.01 μF ATC Chip Cap
C7	30 pF ATC Chip Cap
C10	91 pF ATC Chip Cap
C12, C15	1200 pF ATC Chip Cap
C13, C14, C16, C17	0.01 μF / 500 V Chip Cap
C18	10 μF 63 V Electrolytic Capacitor

175 MHz Test Circuit Photomaster

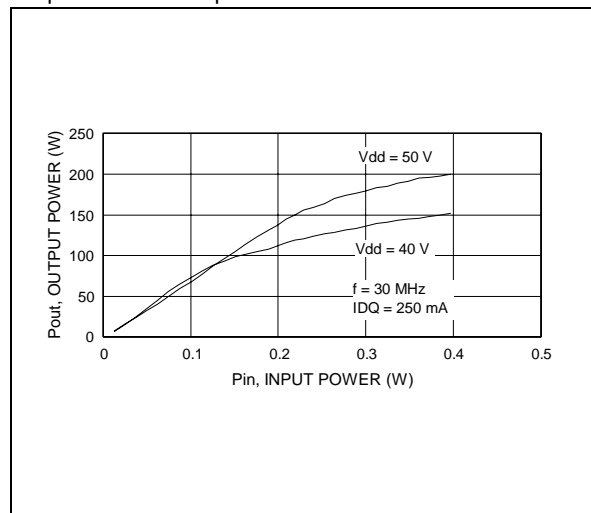


175 MHz Test Circuit

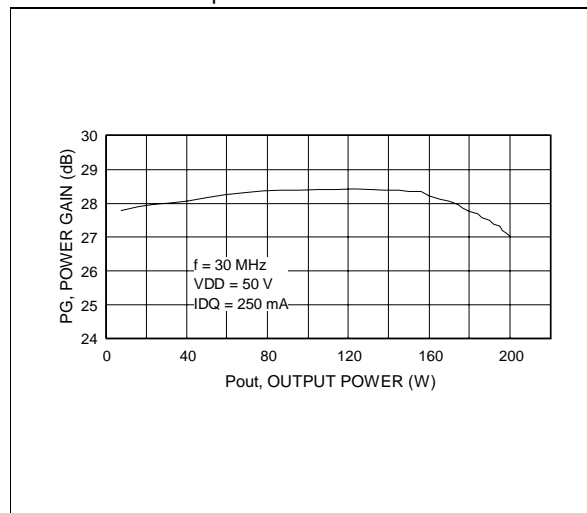


TYPICAL PERFORMANCE (30 MHz)

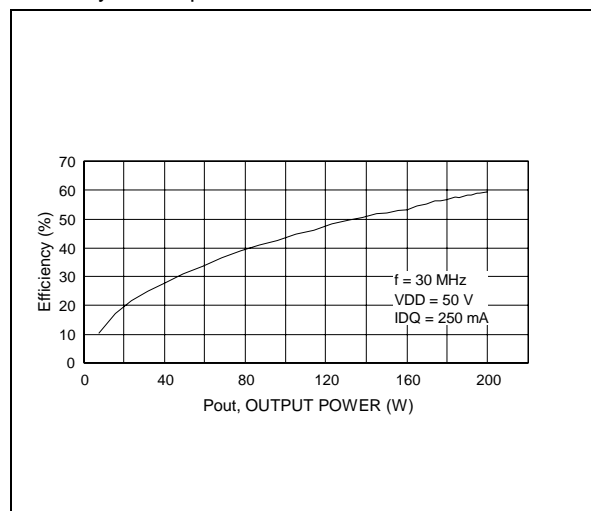
Output Power vs. Input Power



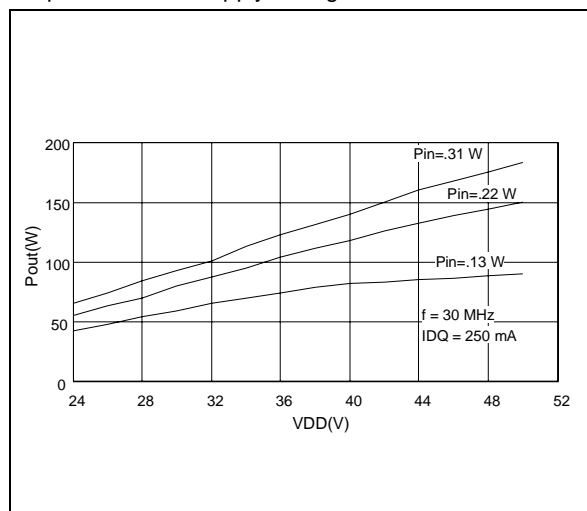
Power Gain vs. Output Power



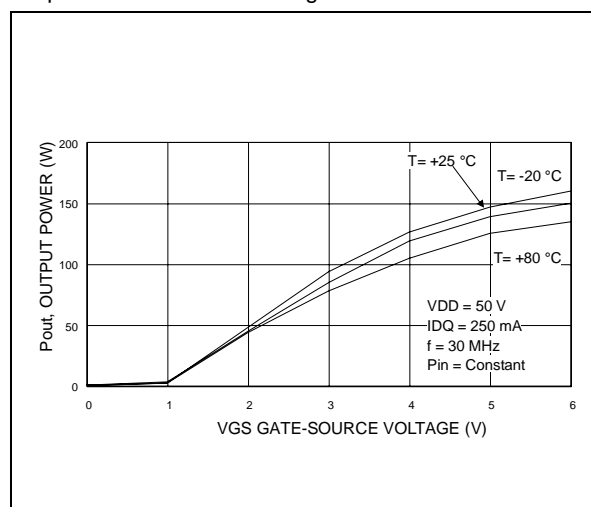
Efficiency vs. Output Power



Output Power vs. Supply Voltage

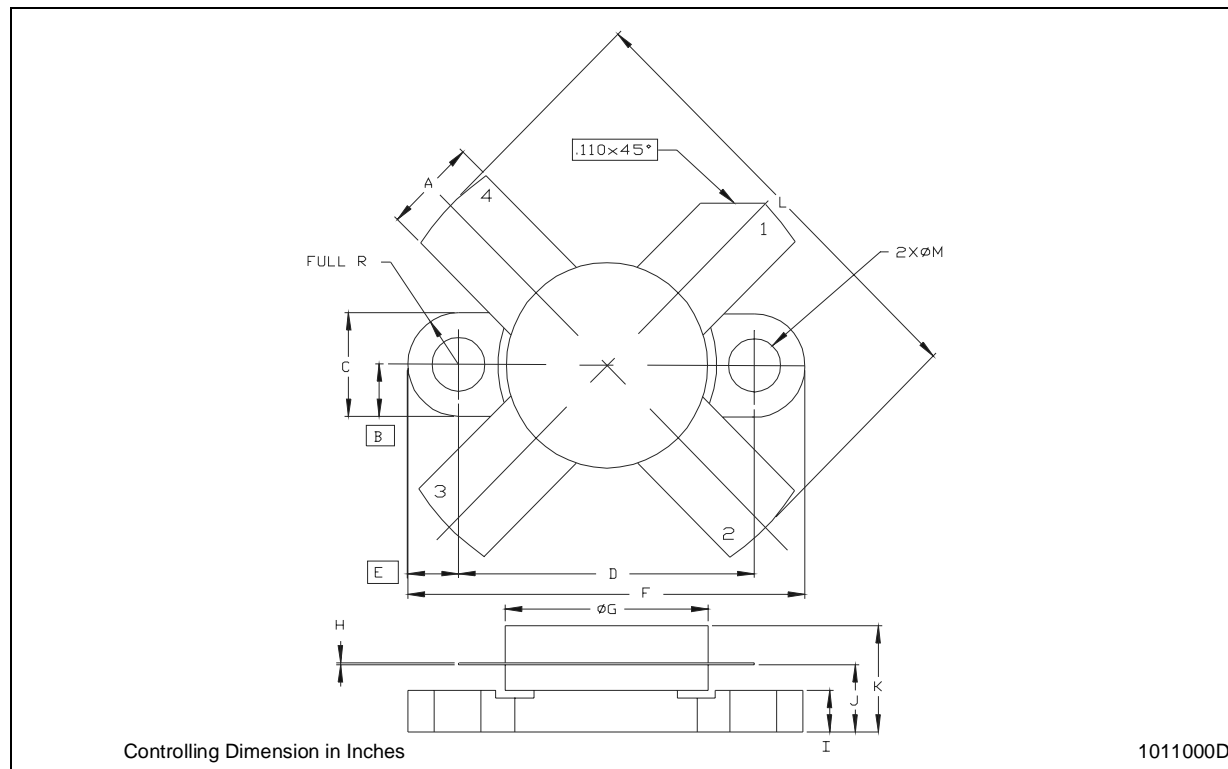


Output Power vs. Gate Voltage



M174 (.500 DIA 4/L N/HERM W/FLG) MECHANICAL DATA

DIM.	mm			Inch		
	MIN.	TYP.	MAX	MIN.	TYP.	MAX
A	5.56		5.584	0.219		0.230
B		3.18			0.125	
C	6.22		6.48	0.245		0.255
D	18.28		18.54	0.720		0.730
E		3.18			0.125	
F	24.64		24.89	0.970		0.980
G	12.57		12.83	0.495		0.505
H	0.08		0.18	0.003		0.007
I	2.11		3.00	0.083		0.118
J	3.81		4.45	0.150		0.175
K			7.11			0.280
L	25.53		26.67	1.005		1.050
M	3.05		3.30	0.120		0.130



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